

FQB22P10TM

Data Sheet

100V P-Channel QFET; Package: TO-263(D2PAK); No of Pins: 2; Container: Tape & Reel,MOSFET 100V P-Channel QFET

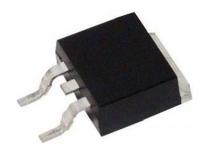
Manufacturers ON Semiconductor, LLC

Package/Case D2PAK

Product Type Transistors

RoHS Rohs

Lifecycle



Images are for reference only

Please submit RFQ for FQB22P10TM or Email to us: sales@ovaga.com We will contact you in 12 hours.



General Description

This P-Channel enhancement mode power MOSFET is produced using a proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features Application

175°C maximum junction temperature rating ONSEMI

Related Products



FQT7N10LTF

ON Semiconductor, LLC SOT-223



FQD19N10LTM

ON Semiconductor, LLC

TO-252



FOPF13N50CF

ON Semiconductor, LLC

TO-220F



FQD12N20LTM

ON Semiconductor, LLC

TO-252



FQA140N10
ON Semiconductor, LLC
TO-3P



ON Semiconductor, LLC TO-220F

FQPF70N10



FQP17P10
ON Semiconductor, LLC
TO-220



FQB5N90TM
ON Semiconductor, LLC
TO-263